

DS10BR254 1.5 Gbps 1:4 LVDS Repeater

Check for Samples: DS10BR254

DESCRIPTION

FEATURES

- DC 1.5 Gbps Low Jitter, Low Skew, Low Power Operation
- Wide Input Common Mode Voltage Range Allows for DC-Coupled Interface to LVDS, CML and LVPECL Drivers
- · Redundant Inputs
- LOS Circuitry Detects Open Inputs Fault Condition
- Integrated 100Ω Input and Output Terminations
- 8 kV ESD on LVDS I/O Pins Protects Adjoining Components
- Small 6 mm x 6 mm WQFN-40 Space Saving Package

APPLICATIONS

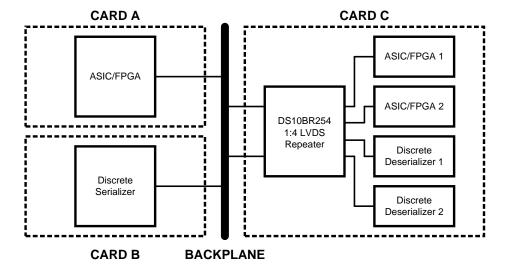
- Clock Distribution
- · Clock and Data Buffering and Muxing
- OC-12 / STM-4
- SD/HD SDI Routers

Typical Application

The DS10BR254 is a 1.5 Gbps 1:4 LVDS repeater optimized for high-speed signal routing and distribution over FR-4 printed circuit board backplanes and balanced cables. Fully differential signal paths ensure exceptional signal integrity and noise immunity.

The device has two different LVDS input channels and a select pin_determines which input is active. A loss-of-signal (LOS) circuit monitors both input channels and a unique LOS pin is asserted when no signal is detected at that input.

Wide input common mode range allows the switch to accept signals with LVDS, CML and LVPECL levels; the output levels are LVDS. A very small package footprint requires a minimal space on the board while the flow-through pinout allows easy board layout. Each differential input and output is internally terminated with a 100Ω resistor to lower device return losses, reduce component count and further minimize board space.

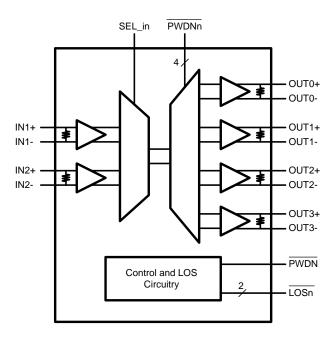


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



Block Diagram



Connection Diagram

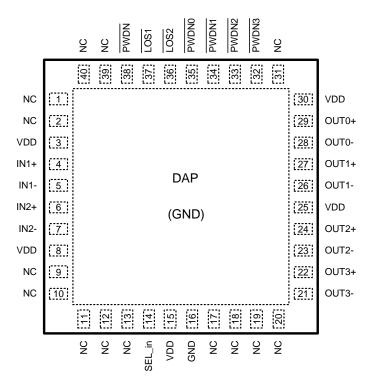


Figure 1. DS10BR254 Pin Diagram See Package Number RTA0040A

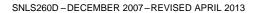
www.ti.com

PIN DESCRIPTIONS

Pin Name	Pin Number	I/O, Type	Pin Description
IN1+, IN1-, IN2+, IN2-,	4, 5, 6, 7,	I, LVDS	Inverting and non-inverting high speed LVDS input pins.
OUT0+, OUT0-, OUT1+, OUT1-, OUT2+, OUT2-, OUT3+, OUT3-	29, 28, 27, 26, 24, 23, 22, 21	O, LVDS	Inverting and non-inverting high speed LVDS output pins.
SEL_in	14	I, LVCMOS	This pin selects which LVDS input is active.
LOS1, LOS2	37, 36	O, LVCMOS	Loss Of Signal output pins, TOSn report when an open input fault condition is detected at the input, INn. These are open drain outputs. External pull up resistors are required.
PWDNO, PWDN1, PWDN2, PWDN3	35, 34 33, 32	I, LVCMOS	Channel output power down pin. When the PWDNn is set to L, the channel output OUTn is in the power down mode.
PWDN	38	I, LVCMOS	Device power down pin. When the PWDN is set to L, the device is in the power down mode.
VDD	3, 8, 15,25, 30	Power	Power supply pins.
GND	16, DAP	Power	Ground pin and a pad (DAP - die attach pad).
NC	1, 2 9, 10, 11, 12, 13, 17, 18, 19, 20, 31, 39, 40	NC	NO CONNECT pins. May be left floating.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.





Absolute Maximum Ratings(1)(2)

Supply Voltage		-0.3V to +4V
LVCMOS Input Voltage	-0.3V to (V _{CC} + 0.3V)	
LVCMOS Output Voltage		-0.3V to (V _{CC} + 0.3V)
LVDS Input Voltage		-0.3V to +4V
Differential Input Voltage VII		1V
LVDS Output Voltage		-0.3V to (V _{CC} + 0.3V)
LVDS Differential Output Vol	age	0.0V to +1V
LVDS Output Short Circuit C	rrent Duration	5 ms
Junction Temperature		+150°C
Storage Temperature Range		−65°C to +150°C
Lead Temperature Range	Soldering (4 sec.)	+260°C
Maximum Package Power	SQA Package	4.65W
Dissipation at 25°C	Derate SQA Package	37.2 mW/°C above +25°C
Package Thermal	θ_{JA}	+26.9°C/W
Resistance	θ_{JC}	+3.8°C/W
ESD Susceptibility	HBM ⁽³⁾	≥8 kV
	MM ⁽⁴⁾	≥250V
	CDM ⁽⁵⁾	≥1250V

^{(1) &}quot;Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions.

- (3) Human Body Model, applicable std. JESD22-A114C
- (4) Machine Model, applicable std. JESD22-A115-A
- (5) Field Induced Charge Device Model, applicable std. JESD22-C101-C

Recommended Operating Conditions

	Min	Тур	Max	Units
Supply Voltage (V _{CC})	3.0	3.3	3.6	V
Receiver Differential Input Voltage (V _{ID})	0		1	V
Operating Free Air Temperature (T _A)	-40	+25	+85	°C

⁽²⁾ If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.



Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
LVCMO	S DC SPECIFICATIONS					
V _{IH}	High Level Input Voltage		2.0		V_{DD}	V
V _{IL}	Low Level Input Voltage		GND		0.8	V
I _{IH}	High Level Input Current	V _{IN} = 3.6V V _{CC} = 3.6V		0	±10	μΑ
I _{IL}	Low Level Input Current	$V_{IN} = GND$ $V_{CC} = 3.6V$		0	±10	μΑ
V_{CL}	Input Clamp Voltage	I _{CL} = -18 mA, V _{CC} = 0V		-0.9	-1.5	V
V _{OL}	Low Level Output Voltage	I _{OL} = 4 mA		0.26	0.4	V
LVDS IN	IPUT DC SPECIFICATIONS					
V _{ID}	Input Differential Voltage		0		1	V
V_{TH}	Differential Input High Threshold	$V_{CM} = +0.05V \text{ or } V_{CC}-0.05V$		0	+100	mV
V_{TL}	Differential Input Low Threshold		-100	0		mV
V_{CMR}	Common Mode Voltage Range	V _{ID} = 100 mV	0.05		V _{CC} - 0.05	V
I _{IN}	Input Current	V _{IN} = +3.6V or 0V V _{CC} = 3.6V or 0V		±1	±10	μΑ
C _{IN}	Input Capacitance	Any LVDS Input Pin to GND		1.7		pF
R _{IN}	Input Termination Resistor	Between IN+ and IN-		100		Ω
LVDS O	UTPUT DC SPECIFICATIONS					
V _{OD}	Differential Output Voltage		250	350	450	mV
ΔV_{OD}	Change in Magnitude of V _{OD} for Complimentary Output States	$R_L = 100\Omega$	-35		35	mV
Vos	Offset Voltage		1.05	1.2	1.375	V
ΔV _{OS}	Change in Magnitude of V _{OS} for Complimentary Output States	$R_L = 100\Omega$	-35		35	mV
Ios	Output Short Circuit Current (4)	OUT to GND		-35	-55	mA
		OUT to V _{CC}		7	55	mA
C _{OUT}	Output Capacitance	Any LVDS Output Pin to GND		1.2		pF
R _{OUT}	Output Termination Resistor	Between OUT+ and OUT-		100		Ω
	CURRENT				•	
I _{CC}	Supply Current	PWDN = H		113	135	mA
I _{CCZ}	Power Down Supply Current	PWDN = L		50	60	mA

⁽¹⁾ The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.

⁽²⁾ Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V_{OD} and ΔV_{OD}.

⁽³⁾ Typical values represent most likely parametric norms for V_{CC} = +3.3V and T_A = +25°C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

⁽⁴⁾ Output short circuit current (I_{OS}) is specified as magnitude only, minus sign indicates direction only.



AC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified.

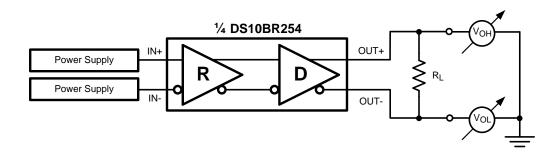
Symbol	Parameter	ditions	Min	Тур	Max	Units	
LVDS OUTPUT	AC SPECIFICATIONS	1			1		-
t _{PLHD}	Differential Propagation Delay Low to High ⁽¹⁾	R. = 1000			440	650	ps
t _{PHLD}	Differential Propagation Delay High to Low ⁽¹⁾	$R_L = 100\Omega$	$R_L = 100\Omega$				
t _{SKD1}	Pulse Skew t _{PLHD} - t _{PHLD} ⁽¹⁾⁽²⁾				40	100	ps
t _{SKD2}	Channel to Channel Skew ⁽¹⁾⁽³⁾				40	125	ps
t _{SKD3}	Part to Part Skew ⁽¹⁾⁽⁴⁾				50	200	ps
t _{LHT}	Rise Time ⁽¹⁾	D 4000			150	300	ps
t _{HLT}	Fall Time ⁽¹⁾	$R_L = 100\Omega$	R _L = 100Ω			300	ps
t _{ON}	Any PWDN to Output Active Time				8	20	μs
t _{OFF}	Any PWDN to Output Inactive Time				5	12	ns
t _{SEL}	Select Time				5	12	ns
JITTER PERFO	PRMANCE ⁽¹⁾	•		•			
t _{RJ1}		V _{ID} = 350 mV	135 MHz		0.5	1	ps
t _{RJ2}	Random Jitter	V _{CM} = 1.2V Clock (RZ)	311 MHz		0.5	1	ps
t _{RJ3}	(RMS Value) ⁽⁵⁾	Oldok (KZ)	503 MHz		0.5	1	ps
t _{RJ4}			750 MHz		0.5	1	ps
t _{DJ1}		$V_{ID} = 350 \text{ mV}$	270 Mbps		6	22	ps
t _{DJ2}	Deterministic Jitter	$V_{CM} = 1.2V$ K28.5 (NRZ)	622 Mbps		6	21	ps
t _{DJ3}	(Peak to Peak Value) ⁽⁶⁾	1120.0 (11112)	1.0625 Gbps		9	18	ps
t _{DJ4}			1.5 Gbps		9	17	ps
t _{TJ1}		V _{ID} = 350 mV	270 Mbps		0.01	0.03	UI _{P-P}
t _{TJ2}	Total Jitter ⁽⁷⁾	$V_{CM} = 1.2V$ PRBS-23 (NRZ)	622 Mbps		0.01	0.03	UI _{P-P}
t _{TJ3}	Total Jiller (**)	1 1100-20 (NIVE)	1.0625 Gbps		0.01	0.04	UI _{P-P}
t _{TJ4}			1.5 Gbps		0.01	0.06	UI _{P-P}

- (1) Specification is specified by characterization and is not tested in production.
- (2) t_{SKD1}, |t_{PLHD} t_{PHLD}|, Pulse Skew, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.
- (3) t_{SKD2}, Channel to Channel Skew, is the difference in propagation delay (t_{PLHD} or t_{PHLD}) among all output channels in Broadcast mode (any one input to all outputs).
- (4) t_{SKD3}, Part to Part Skew, is defined as the difference between the minimum and maximum differential propagation delays. This specification applies to devices at the same V_{CC} and within 5°C of each other within the operating temperature range.
- (5) Measured on a clock edge with a histogram and an accumulation of 1500 histogram hits. Input stimulus jitter is subtracted geometrically.
- (6) Tested with a combination of the 1100000101 (K28.5+ character) and 0011111010 (K28.5- character) patterns. Input stimulus jitter is subtracted algebraically.
- (7) Measured on an eye diagram with a histogram and an accumulation of 3500 histogram hits. Input stimulus jitter is subtracted.

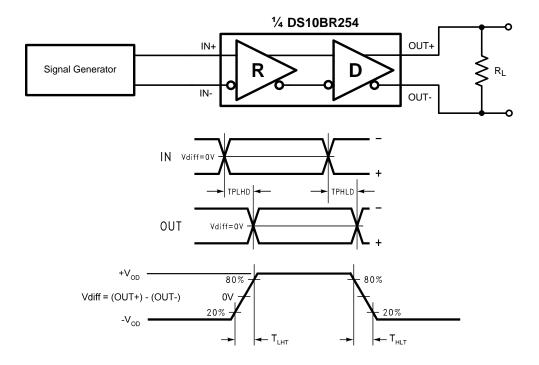


APPLICATION INFORMATION

DC TEST CIRCUITS



AC TEST CIRCUITS AND TIMING DIAGRAMS



Copyright © 2007–2013, Texas Instruments Incorporated



FUNCTIONAL DESCRIPTION

The DS10BR254 is a 1.5 Gbps 1:4 LVDS repeater optimized for high-speed signal routing and distribution over lossy FR-4 printed circuit board backplanes and balanced cables.

Table 1. Input Select Truth Table

CONTROL Pin (SEL_in) State	Input Selected
0	IN1
1	IN2

Input Interfacing

The DS10BR254 accepts differential signals and allows simple AC or DC coupling. With a wide common mode range, the DS10BR254 can be DC-coupled with all common differential drivers (i.e. LVPECL, LVDS, CML). The following three figures illustrate typical DC-coupled interface to common differential drivers. Note that the DS10BR254 inputs are internally terminated with a 100Ω resistor.

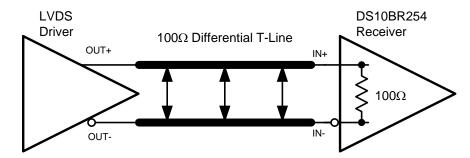


Figure 2. Typical LVDS Driver DC-Coupled Interface to an DS10BR254 Input

Figure 3. Typical CML Driver DC-Coupled Interface to an DS10BR254 Input

Submit Documentation Feedback

CML3.3V or CML2.5V



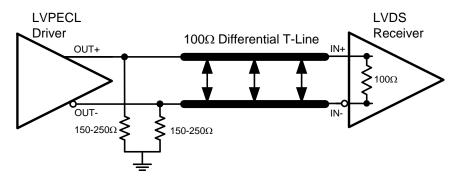


Figure 4. Typical LVPECL Driver DC-Coupled Interface to an DS10BR254 Input

Output Interfacing

The DS10BR254 outputs signals compliant to the LVDS standard. Its outputs can be DC-coupled to most common differential receivers. The following figure illustrates typical DC-coupled interface to common differential receivers and assumes that the receivers have high impedance inputs. While most differential receivers have a common mode input range that can accommodate LVDS compliant signals, it is recommended to check respective receiver's data sheet prior to implementing the suggested interface implementation.

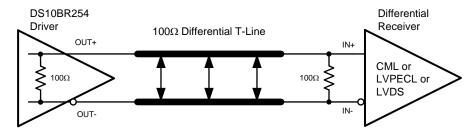


Figure 5. Typical DS10BR254 Output DC-Coupled Interface to an LVDS, CML or LVPECL Receiver



Typical Performance

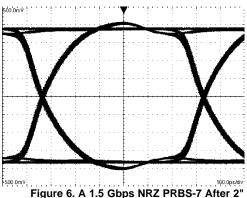


Figure 6. A 1.5 Gbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:100 ps / DIV

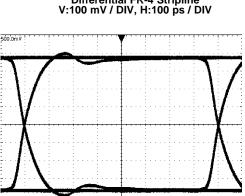


Figure 8. A 622 Mbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:200 ps / DIV

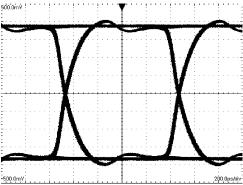


Figure 7. A 1.06 Gbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:200 ps / DIV

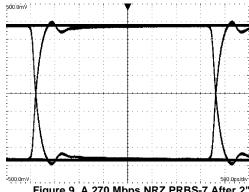


Figure 9. A 270 Mbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:500 ps / DIV

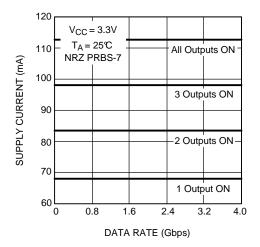


Figure 10. Supply Current as a Function of a Number of Outputs Used



REVISION HISTORY

CI	hanges from Revision C (April 2013) to Revision D	Page
•	Changed layout of National Data Sheet to TI format	10



PACKAGE OPTION ADDENDUM

6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
DS10BR254TSQ/NOPB	ACTIVE	WQFN	RTA	40	250	Green (RoHS & no Sb/Br)	SN	Level-3-260C-168 HR	-40 to 85	1BR254SQ	Samples
DS10BR254TSQX/NOPB	ACTIVE	WQFN	RTA	40	2500	Green (RoHS & no Sb/Br)	SN	Level-3-260C-168 HR	-40 to 85	1BR254SQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





6-Feb-2020

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Sep-2016

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

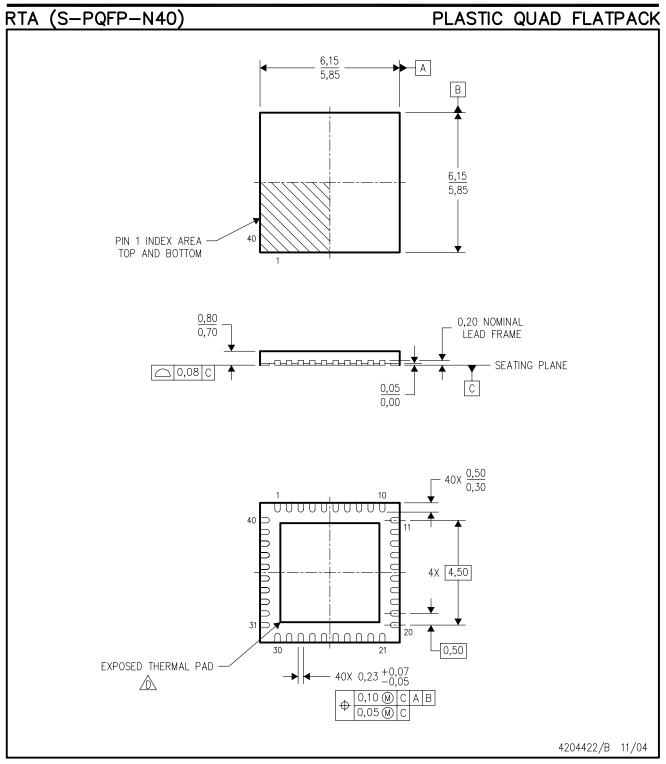
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS10BR254TSQ/NOPB	WQFN	RTA	40	250	178.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1
DS10BR254TSQX/NOPB	WQFN	RTA	40	2500	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1

www.ti.com 20-Sep-2016



*All dimensions are nominal

Device	Package Type	ge Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
DS10BR254TSQ/NOPB	WQFN	RTA	40	250	210.0	185.0	35.0
DS10BR254TSQX/NOPB	WQFN	RTA	40	2500	367.0	367.0	38.0



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) Package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.

 See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

Tl's products are provided subject to Tl's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such Tl products. Tl's provision of these resources does not expand or otherwise alter Tl's applicable warranties or warranty disclaimers for Tl products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2020, Texas Instruments Incorporated